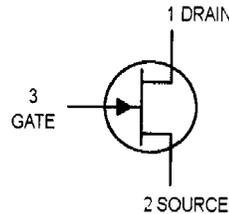
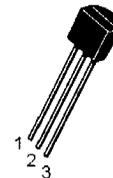


JFET VHF/UHF Amplifiers

N-Channel — Depletion



2N5484
2N5486



TO-92

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Gate Voltage	V_{DG}	25	Vdc
Reverse Gate-Source Voltage	V_{GSR}	25	Vdc
Drain Current	I_D	30	mAdc
Forward Gate Current	$I_{G(f)}$	10	mAdc
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	350 2.8	mW mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

Gate-Source Breakdown Voltage ($I_G = -1.0 \mu\text{Adc}$, $V_{DS} = 0$)	$V_{(BR)GSS}$	-25	—	—	Vdc
Gate Reverse Current ($V_{GS} = -20 \text{Vdc}$, $V_{DS} = 0$) ($V_{GS} = -20 \text{Vdc}$, $V_{DS} = 0$, $T_A = 100^\circ\text{C}$)	I_{GSS}	— —	— —	-1.0 -0.2	nAdc μAdc
Gate Source Cutoff Voltage ($V_{DS} = 15 \text{Vdc}$, $I_D = 10 \text{nAdc}$)	$V_{GS(off)}$	-0.3 -2.0	— —	-3.0 -6.0	Vdc

ON CHARACTERISTICS

Zero-Gate-Voltage Drain Current ($V_{DS} = 15 \text{Vdc}$, $V_{GS} = 0$)	I_{DSS}	1.0 8.0	— —	5.0 20	mAdc
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SMALL-SIGNAL CHARACTERISTICS

Forward Transfer Admittance ($V_{DS} = 15 \text{Vdc}$, $V_{GS} = 0$, $f = 1.0 \text{kHz}$)	$ y_{fs} $	3000 4000	— —	6000 8000	μhos
Input Admittance ($V_{DS} = 15 \text{Vdc}$, $V_{GS} = 0$, $f = 100 \text{MHz}$) ($V_{DS} = 15 \text{Vdc}$, $V_{GS} = 0$, $f = 400 \text{MHz}$)	$\text{Re}(y_{is})$	— —	— —	100 1000	μhos
Output Admittance ($V_{DS} = 15 \text{Vdc}$, $V_{GS} = 0$, $f = 1.0 \text{kHz}$)	$ y_{os} $	— —	— —	50 75	μhos
Output Conductance ($V_{DS} = 15 \text{Vdc}$, $V_{GS} = 0$, $f = 100 \text{MHz}$) ($V_{DS} = 15 \text{Vdc}$, $V_{GS} = 0$, $f = 400 \text{MHz}$)	$\text{Re}(y_{os})$	— —	— —	75 100	μhos
Forward Transconductance ($V_{DS} = 15 \text{Vdc}$, $V_{GS} = 0$, $f = 100 \text{MHz}$) ($V_{DS} = 15 \text{Vdc}$, $V_{GS} = 0$, $f = 400 \text{MHz}$)	$\text{Re}(y_{fs})$	2500 3500	— —	— —	μhos

2N5484 2N5486

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Typ	Max	Unit
SMALL-SIGNAL CHARACTERISTICS (continued)					
Input Capacitance ($V_{DS} = 15\text{ Vdc}$, $V_{GS} = 0$, $f = 1.0\text{ MHz}$)	C_{iss}	—	—	5.0	pF
Reverse Transfer Capacitance ($V_{DS} = 15\text{ Vdc}$, $V_{GS} = 0$, $f = 1.0\text{ MHz}$)	C_{rss}	—	—	1.0	pF
Output Capacitance ($V_{DS} = 15\text{ Vdc}$, $V_{GS} = 0$, $f = 1.0\text{ MHz}$)	C_{oss}	—	—	2.0	pF

FUNCTIONAL CHARACTERISTICS

Noise Figure ($V_{DS} = 15\text{ Vdc}$, $V_{GS} = 0$, $R_G = 1.0\text{ Megohm}$, $f = 1.0\text{ kHz}$) ($V_{DS} = 15\text{ Vdc}$, $I_D = 1.0\text{ mAdc}$, $R_G = 1.0\text{ k}\Omega$, $f = 100\text{ MHz}$) ($V_{DS} = 15\text{ Vdc}$, $I_D = 1.0\text{ mAdc}$, $R_G = 1.0\text{ k}\Omega$, $f = 200\text{ MHz}$) ($V_{DS} = 15\text{ Vdc}$, $I_D = 4.0\text{ mAdc}$, $R_G = 1.0\text{ k}\Omega$, $f = 100\text{ MHz}$) ($V_{DS} = 15\text{ Vdc}$, $I_D = 4.0\text{ mAdc}$, $R_G = 1.0\text{ k}\Omega$, $f = 400\text{ MHz}$)	 2N5484 2N5484 2N5486 2N5486	NF	—	—	2.5	dB
			—	—	3.0	
			—	4.0	—	
			—	—	2.0	
			—	—	4.0	
Common Source Power Gain ($V_{DS} = 15\text{ Vdc}$, $I_D = 1.0\text{ mAdc}$, $f = 100\text{ MHz}$) ($V_{DS} = 15\text{ Vdc}$, $I_D = 1.0\text{ mAdc}$, $f = 200\text{ MHz}$) ($V_{DS} = 15\text{ Vdc}$, $I_D = 4.0\text{ mAdc}$, $f = 100\text{ MHz}$) ($V_{DS} = 15\text{ Vdc}$, $I_D = 4.0\text{ mAdc}$, $f = 400\text{ MHz}$)	 2N5484 2N5484 2N5486 2N5486	G_{ps}	16	—	25	dB
			—	14	—	
			18	—	30	
			10	—	20	